Monolithic Amplifier

DC-2 GHz

Product Features

- DC-2 GHz
- Single Voltage Supply
- Internally Matched to 50 Ohm
- Unconditionally Stable
- Low Performance Variation Over Temperature
- Transient Protected
- Aqueous washable
- Protected By US Patent 6,943,629

Typical Applications

- Cellular/ PCS/ 3G Base Station
- CATV, Cable Modem & DBS
- Fixed Wireless & WLAN
- Microwave Radio & Test Equipment



CASE STYLE: WW107 PRICE: \$1.37 ea. QTY. (30)

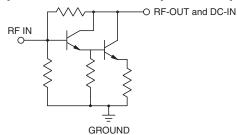
+ RoHS compliant in accordance with EU Directive (2002/95/EC)

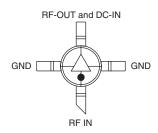
The +Suffix has been added in order to identify RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications.

General Description

ERA-8SM+ (RoHS compliant) is a wideband amplifier offering high dynamic range. It has repeatable performance from lot to lot. It is enclosed in a Micro-X package. ERA-8SM+ uses Darlington configuration and is fabricated using InGaP HBT technology. Expected MTBF is 13,000 years at 85°C case temperature.

simplified schematic and pin description

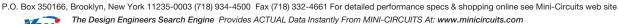




Function	Pin Number	Description
RF IN 1 RF input pin. This pin requires the use of an external DC blocking for the frequency of operation.		RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
RF-OUT and DC-IN	3	RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit".
GND	2,4	Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance.







Electrical Specifications at 25°C and 36mA, unless noted

Parameter		Min.	Тур.	Max.	Units	Cpk
Frequency Range*		DC		2	GHz	
Gain	f=0.1 GHz	29.3	31.5	32.3	dB	≥ 1.5
	f=1 GHz	22.9	24.4	25.9		
	f=2 GHz		19			
	f=3 GHz		15			
	f=4 GHz		12			
Magnitude of Gain Variation versus Temperature	f=0.1 GHz		.0079	.016	dB/°C	
(values are negative)	f=1 GHz		.0071	.016		
,	f=2 GHz		.0076	.016		
	f=3 GHz		.0089			
	f=4 GHz		.0095			
Input Return Loss	f=0.1 GHz		14.5		dB	
	f=1 GHz		16			
	f=2 GHz		15			
	f=3 GHz		13			
	f=4 GHz		10			
Output Return Loss	f=0.1 GHz		12		dB	
	f=1 GHz		13.5			
	f=2 GHz		12			
	f=3 GHz		10			
	f=4 GHz		8			
Reverse Isolation	f=2 GHz	20	23		dB	
Output Power @ 1 dB compression	f=0.1 GHz		12.5		dBm	≥ 1.33
·	f=1 GHz	10	12.5			
	f=2 GHz		10.5			
	f=3 GHz		7.5			
Saturated Output Power	f=0.1 GHz		14.9		dBm	
(at 3dB compression)	f=1 GHz		13.7			
	f=2 GHz		11.9			
	f=3 GHz		8.7			
Output IP3	f=0.1 GHz	24	27		dBm	≥ 1.33
	f=1 GHz	22	25			
	f=2 GHz	18	21.5			
	f=3 GHz		18			
Noise Figure	f=0.1 GHz		2.2	3	dB	
	f=1 GHz		2.8	3.8		
	f=2 GHz		3	4		
Group Delay	f=1 GHz		130		psec	
Recommended Device Operating Current			36		mA	
Device Operating Voltage		3.5	3.7	3.9	V	≥ 1.5
Device Voltage Variation vs. Temperature at 36mA			-0.5		mV/°C	
Device Voltage Variation vs. Current at 25°C			6.4		mV/mA	
Thermal Resistance, junction-to-case ¹			140		°C/W	

^{*}Guaranteed specification DC-2 GHz. Low frequency cut off determined by external coupling capacitors.

Absolute Maximum Ratings

Absolute Maximum Hattings			
Parameter	Ratings		
Operating Temperature*	-45°C to 85°C		
Storage Temperature	-65°C to 150°C		
Operating Current	65mA		
Power Dissipation	250mW		
Innut Power	13dBm		

Note: Permanent damage may occur if any of these limits are exceeded. These ratings are not intended for continuous normal operation.

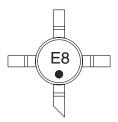
¹Case is defined as ground leads.

^{*}Based on typical case temperature rise 5°C above ambient.





Product Marking



Additional Detailed Technical Information

Additional information is available on our web site. To access this information enter the model number on our web site home page.

Performance data, graphs, s-parameter data set (.zip file)

Case Style: WW107

Plastic micro-x, .085 body diameter, lead finish: tin/silver/nickel

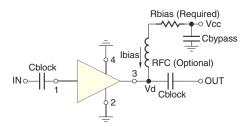
Tape & Reel: F4

Suggested Layout for PCB Design: PL-075

Evaluation Board: TB-408-8+

Environmental Ratings: ENV08T2

Recommended Application Circuit



Test Board includes case, connectors, and components (in bold) soldered to PCB

R BIAS				
Vcc	"1%" Res. Values (ohms) for Optimum Biasing			
7	88.7			
8	118			
9	143			
10	174			
11	200			
12	232			
13	255			
14	280			
15	309			
16	340			
17	365			
18	392			
19	422			
20	453			





ESD Rating

Human Body Model (HBM): Class 1B (500 v to < 1,000 v) in accordance with ANSI/ESD STM 5.1 - 2001

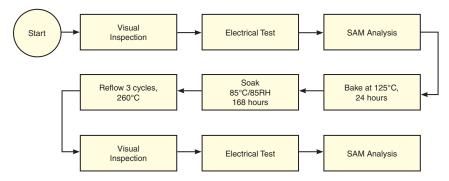
Machine Model (MM): Class M1 (< 100 v) in accordance with ANSI/ESD STM 5.2 - 1999

MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDECJ-STD-020C

No.	Test Required	Condition	Standard	Quantity
1	Visual Inspection	Low Power Microscope Magnification 40x	MIP-IN-0003 (MCT spec)	45 units
2	Electrical Test	Room Temperature	SCD (MCL spec)	45 units
3	SAM Analysis	Less than 10% growth in term of delamination	in term of J-Std-020C (Jedec Standard)	
4	Moisture Sensitivity Level 1	I Shak at 85°C/85% RH for 168 hours 1		45 units

MSL Test Flow Chart





RF/IF MICROWAVE COMPONENTS

